Investigation on the escaped and trapped emission in organic light-emitting devices

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1. Introduction

Organic light emitting devices (OLEDs) are receiving a great deal of attention for their potential application in flat panel display and illumination [1]. Although an internal quantum efficiency of nearly 100% has been achieved [2,3], due to the mismatch of the refractive index of air, glass substrate, and organic layer, a lot of the generated light is lost through total internal reflection into substrate and indium-tin-oxide (ITO) wave-guiding modes, and to self-absorption. So the external coupling efficiency ($\eta_{\text{ext}}$ defined in Eq. (1)) is a critical figure for OLED. The $\eta_{\text{ext}}$ is calculated by classical ray optics to be $1/2n^2$, where $n$ is the refractive index of substrate [4]. For glass substrate ($n=1.52$), the calculated external coupling efficiency is about 20%, which means 80% of the generated light is wasted. Because of this amazing optical loss in theory, many methods were developed to enhance the efficiency. For example, the surface and edges of glass substrate were roughened to extract the light in the glass substrate, and get a 22% improvement of efficiency [5]. Other methods, such as the spherically shaped patterns [6], the textured meshed surfaces [7], the ordered micro-lens arrays [8,9], the silica micro-spheres [10,11], and the diffusive layer [12-14] were used to reduce the light trapped in the glass substrates. According to the classical ray optics model, the external coupling efficiency can be enhanced by several times by reducing the trapped light. However, contrary to this prediction, the above mentioned methods only achieved an efficiency enhancement of from 22% to 56%.

In fact, the classical ray optics model neglects the interference effect between the reflective electric field and the dipole radiated field, so the external coupling efficiency is underestimated. In order to analyze the external coupling efficiency accurately, several theoretical models have been developed in previous reports [15-20]. Based on optical interference, a “half-space” dipole model was developed [15], and gave a calculated $\eta_{\text{ext}}$ of 26%. In Forrest's report [16], quantum mechanics is used to simulate the behavior of radiating molecules in OLED, and the calculated $\eta_{\text{ext}}$ is 56%. In addition, M.-H. Lu developed a combined classical and quantum mechanical microwavability model (CCQMM) [17] and the calculated $\eta_{\text{ext}}$ is 23.5%. Recently, the group of Alongkarn Chutinan [18] and Benjamin C. Krummacher [19,20] developed the finite difference time domain method and optical loss mechanisms models to theoretically calculate the $\eta_{\text{ext}}$ as about 25%.

The external coupling efficiency ($\eta_{\text{ext}}$) cannot be measured directly in experiment. Because of the large absorption coefficients of ITO and organic materials, the light trapped in the ITO/org layer is absorbed before zigzagging to the edges, and can not be collected. Only the light flux of escaped and trapped in the glass substrate can be measured, so the external coupling ratio ($r_{\text{ext}}$ defined in Eq. (2)), namely the ratio of the escaped to the sum of the escaped and the trapped emission in the glass substrate, can be more easily obtained in experiment.

In previous reports [15-20], the external coupling efficiency or ratio, was also measured to verify their theoretical results. In M.-H. Lu' work [17], silicon photodiodes on a stage with azimuthally rotation were used to obtain the photon flux of the edge and surface of OLED,
and then obtained \( r_{\text{ext}} \) of 42% and 32% for Alq3 based devices with 100 nm and 200 nm ITO thickness respectively [17]; and according to the report of Kim [15], the flux at a given angle was measured by charge coupled device spectrograph, then the total photon flux was obtained by spectral integration, and the \( r_{\text{ext}} \) is about 52%. More comparisons between the experimental and theoretical results are summarized in Table 1. These different results still did not present us how much generated light can be effectively decoupled from the devices, so further investigations on the external coupling ratio, \( r_{\text{ext}} \), of OLEDs are required.

In this paper, using the integrating sphere, fiber spectrometer and glass hemisphere, we could directly get the photon flux of the edges and surface of tris-8-hydroxyquinoline aluminum (Alq3) based OLEDs, then the external coupling ratio, \( r_{\text{ext}} \) of 56% is obtained. Furthermore, we extended the “half-space” dipole model by taking dipole radiation pattern into account, then calculated the angular distribution pattern of the emission in OLED, and finally obtained the external coupling ratio in theory.

2. Experiment and measurement methods

2.1. The structures of the devices

The OLED structure used in both experiment and modeling is shown in Fig. 1(a). On the glass substrate, the indium-tin-oxide (ITO) layer is used as anode \((n_{\text{ITO}}=1.9, \text{ thickness}=100 \text{ nm}, 135 \text{ nm, or } 170 \text{ nm})\). A copper phthalocyanine (CuPc) thin film with a thickness of 15 nm is used as the hole injection layer, a N,N'-bis (Inaphthyl)-N,N'-diphenyl-1, 1'-biphenyl-4,4'-diamine (NPB) with a thickness of 40 nm is used as a hole transport layer, and a tris-8-hydroxyquinoline aluminum (Alq3) based OLEDs, then the external coupling ratio, \( r_{\text{ext}} \) of 56% is obtained. Furthermore, we extended the “half-space” dipole model by taking dipole radiation pattern into account, then calculated the angular distribution pattern of the emission in OLED, and finally obtained the external coupling ratio in theory.

2.2. Optical modes and the external coupling efficiency

The optical structure of the device is shown in Fig. 1(c). The emission region is at the interface between the layers of NPB and Alq3. The emission layer is bounded by the metal cathode and the ITO-glass substrate with an interface with air. Due to the total internal reflection, we can divide the emission light into three modes by their corresponding angular ranges [17].

First, the external modes: when the photons with the internal emission angle \( \theta \) is in the range: \( 0 \leq \theta \leq \theta_1, \theta_1 = \sin^{-1}(n_{\text{ITO}}/n_p) \), the photons will escape from the surface; second, the substrate modes: when the internal emission angle \( \theta \) is in the range: \( \theta_1 < \theta \leq \theta_2, \theta_2 = \sin^{-1}(n_{\text{Alq3}}/n_p) \), these modes will emerge through the substrate edge after several reflections; lastly, the ITO/organic modes: when the internal emission angle \( \theta \) is in the range: \( \theta_2 < \theta \leq \pi/2 \), where \( n_p \) and \( n_e \) are the refractive indices of air and the emitter layer, and \( n_p \) is the refractive index of the glass substrate. And then the external coupling efficiency can be defined by the following equations respectively:

\[
\eta_{\text{ext}} = \frac{\text{external modes}}{(\text{external modes} + \text{substrate modes} + \text{ITO/organic modes})}
\]

In fact, the absorption coefficient of ITO is on the order of 5000 cm\(^{-1}\) [22], so the ITO/organic modes can not be detected from the edges. A part of the substrate modes are absorbed by the OLED when zigzagging to the substrate edges, so the measured value of these modes is underestimated and should be corrected to get the real value. Then the \( \eta_{\text{ext}} \) can not be measured directly, and only the external coupling ratio \( (r_{\text{ext}}) \) can be obtained as the following equations:

\[
r_{\text{ext}} = \frac{\text{external modes} + \text{correctional substrate modes}}{\text{external modes} + \text{substrate modes} + \text{ITO/organic modes}}
\]

2.3. Measurement method

In the previous reports [15-17], silicon photodiode (or silicon photodiode arrays) and charge coupled device spectrograph are the most widely used detectors for the electroluminescence (EL) measurements of OLEDs. This can only detect the discrete emission intensity at a given angle, and the discrete values were added to get the total photon flux. It could not directly obtain the flux, and is easy to induce measurement errors. In our research, the photon flux of devices was measured by an integrating sphere (SLM-12, Sphere Optics LLC) combined with a fiber spectrometer (USB 2000+, Ocean Optics Inc.), shown in Fig. 1(d). The diameter of the integrating sphere is 250 cm, which is much greater than the size of the emitting area, and the dimension is suitable for decreasing the instrumental error. And a glass hemisphere is also used in our measurement, which can extract almost all of the substrate modes into external coupling modes. Similar measurement method is also used in other works [23-26]. The fiber spectrometer features high sensitivity, stable quantum efficiency over a certain wavelength range, and near-linear response with the incident light power. And the integrating sphere can collect all of the light emitted from the OLED.

In order to measure the external modes, substrate modes, the “Absorber 1” and “Absorber 2” were used, which is shown in Fig. 1(a). First, the prepared OLED with the edges of the substrate was covered by “Absorber 2,” and it was lighted under a given voltage and current, then the measured flux \( F_{\text{ITOf}} \) is external modes; second, with the emitting areas covered by “glass hemisphere,” and then we got the total optical output \( F_{\text{ITOf}} \); third, the edges of the substrate were covered by “Absorber 2,” and the emitting area was still covered by “glass hemisphere,” then the measured flux \( F_{\text{ITOf}} \) is the sum of the external modes \( F_{\text{ITOf}} \) and the extracted substrate modes \( F_{\text{ITOf} \text{org}} \); fourth, with the emitting areas covered by “glass hemisphere” and “Absorber 1,” the flux, \( F_{\text{org}} \) is the sum of unextracted substrate modes, \( F_{\text{ITOf} \text{org}} \) and ITO/organic modes \( F_{\text{ITOf} \text{org}} \); lastly, the “Absorber 1,” “Absorber 2” and “hemisphere prism” were all covered on all edges and surface of the substrate, and then, the flux \( F_{3} \) of ITO/organic modes \( (F_{\text{ITOf} \text{org}}) \) could be obtained.

<table>
<thead>
<tr>
<th>Group (or authors)</th>
<th>Measured ( r_{\text{ext}} )</th>
<th>Calculated ( r_{\text{ext}} )</th>
<th>Calculated ( \eta_{\text{ext}} )</th>
<th>Condition</th>
</tr>
</thead>
<tbody>
<tr>
<td>Forrest et al. [16]</td>
<td>62%</td>
<td>61%</td>
<td>56%</td>
<td>ITO (160 nm)/CuPc/α-NPD/Alq3 (60 nm)/MgAg</td>
</tr>
<tr>
<td>J. Kim et al. [15]</td>
<td>52%</td>
<td>54%</td>
<td>26%</td>
<td>ITO/HTL/small molecule emitting layer/MgAg</td>
</tr>
<tr>
<td>M. Lu et al. [17]</td>
<td>42%</td>
<td>38%</td>
<td>23.5%</td>
<td>ITO (100 nm)/PVK/Alq3 (60 nm)/MgAg</td>
</tr>
<tr>
<td>Noda et al. [18]</td>
<td>40%</td>
<td>38%</td>
<td>25%</td>
<td>ITO (150 nm)/PVK (40 nm)/Alq3 (60 nm)/Al</td>
</tr>
<tr>
<td>Nowy et al. [19]</td>
<td>38%</td>
<td>38%</td>
<td>23%</td>
<td>ITO (50 nm)/Alq3 (160 nm)/Ca (15 nm)/Al</td>
</tr>
</tbody>
</table>

Table 1 Summary of the measured and calculated external coupling ratio and conditions in the literature.
An index-matching fluid is applied between the hemisphere and the OLEDs, with the same refractive index as the glass substrate, to ensure proper optical contact. In the five steps, the OLED was lightened under the same current density ($r_{\text{ext}}$ does not change with current density), and the measurement is rapidly accomplished, so the attenuation of devices is negligible.

The absorption coefficient of ITO and organic material is the order of magnitude of 5000 cm$^{-1}$ [22], so the light of the ITO/organic modes can almost not escape the layers before dissipation, and $F_3 = 0$. The absorption of the glass substrate at the wavelength of about 520 nm is very low, and the light is severally reflected at the metal cathode surface when zigzagging to the substrate edges; the metal cathode absorbs a part of energy (Fig. 2). So the real value of the unextracted substrate modes ($F_1'$) can be obtained by retrieving the absorption of metal cathode and glass, and the total flux of the external modes and substrate modes is ($F_1' + F_2$). And then, the external coupling ratio ($r_{\text{ext}}$) is calculated by Eq. (3), and it is shown in Fig. 4.

$$r_{\text{ext}} = F_1' / (F_1' + F_2)$$  \hspace{1cm} (3)

After the first measurement, we change the glass substrate size as 30 mm $\times$ 37 mm, 27 mm $\times$ 32 mm, and 25 mm $\times$ 26 mm (in Fig. 1(b)), the emission areas not changing, and remeasure the devices. The results do not alter, so the substrate size does not affect the value of $r_{\text{ext}}$.

3. Results and discussion

3.1. Experimental data

The fluxes of the total emitted light, the external modes, substrate modes, and ITO/organic modes are obtained by the measurement. The external coupling ratio ($r_{\text{ext}}$) is calculated by Eq. (2), and it is shown in Fig. 3. The $r_{\text{ext}}$ is from 20% to 56%, which varies with the thickness of Alq$_3$, and there is about 5% measurement error. After the first measurement, we change the glass substrate size as 30 mm $\times$ 37 mm, 27 mm $\times$ 32 mm, and 25 mm $\times$ 26 mm (in Fig. 1(b)), the emission areas not changing, and remeasure the devices. The results do not alter, so the substrate size does not affect the value of $r_{\text{ext}}$.
27 mm × 32 mm, and 25 mm × 26 mm (in Fig. 1(b)), the emission areas not changing, and remeasure the devices. The results do not alter, so the substrate size does not affect the value of rext.

In addition, from the experiment data, when the thickness of ITO is 100 nm, 135 nm, and 170 nm, the rext almost does not alter. This phenomenon is consistent with Kim’s results [27]. Generally, the number of the optical waveguide modes can be simply calculated by Eq. (4) [28].

$$M = \frac{4d}{\lambda} \sqrt{n_i^2 - n_g^2}$$  \hspace{1cm} (4)

Here, d is the thickness of ITO/organic layer, n_i and n_g are the refractive indices of ITO/organic layer and glass substrate respectively, and λ is the wavelength of light emitted by Alq3. From this equation, the ITO/organic layer can only support the zero-order or zero-order and first-order wave-guiding modes for ITO of 100 nm, 135 nm, and 170 nm. Then, only the emitted light at certain angle can couple to zero-order or first-order wave-guiding modes, and the other parts of the light are still in this layer, but can not form wave-guiding modes, and will be dissipated ultimately. So, for the different thickness of ITO, the flux of light emitted to the ITO/organic modes does not alter, and then the intensity of the ITO/organic mode and the external coupling ratio do not alter.

3.2. Extended “half-space” dipole model by taking dipole radiation pattern into account

From the experimental data, our maximal rext is about 56%, which is a little higher than previous calculations. According to the previous work [15], for the “half-space” dipole model, the light emitted by dipoles is considered as to be isotropic. In fact, the emission of a dipole is not isotropic, its spatial radiation intensity varies with the emission angle [29]. In order to accurately investigate the rext, we extended the “half-space” dipole model by taking dipole radiation pattern into account. In our model, the emission of organic layer is considered as oscillating dipoles emission in front of a mirror [30]. This emission layer is the Alq3 layer for our devices. These dipoles are embedded inside the emitter half space at a distance z from the mirror (Al cathode-reflector in Fig. 1(a)). The other half space is occupied by the Al cathode. The emission of a dipole is anisotropic, so these dipoles should be divided into three freedoms for calculation, as shown in Fig. 4. This model is also able to represent the interference between the directly emitted light and the light reflected by the metal cathode. And then, it will calculate the angular distribution of the radiation intensity, and then extract the external coupling ratio. In OLEDs, the energy coupled to surface plasmon modes is by the near field effect of dipoles [31,32], so it is nonradioactive losses, and it does not alter the emission patterns of OLEDs. So in our model, we did not take the surface plasmon losses into account.

As shown in Fig. 4, for the emitting dipoles at distance d from the interface of metal cathode and organic layers, the angular distribution for emission intensity (I) of dipoles can be written as the following [30]:

$$I(\theta) = E_x^2[1 + r_p \exp(2i\delta \cos \theta)]^2 + E_y^2[1 - r_p \exp(2i\delta \cos \theta)]^2$$  \hspace{1cm} (5)

$$+ E_z^2[1 + r_e \exp(2i\delta \cos \theta)]^2$$

Here, $r_p$ and $r_e$ is the Fresnel reflection coefficient for the s- and p-polarization, $\theta$ is the internal emission angle and also the direction of the Poynting vector. $\delta$ is the phase change incurred in the round trip from the emitter to the organic/cathode interface and back, and $\delta = 2\pi m d / \lambda_0$, where $\lambda_0$ is the emission center wavelength in vacuum and $n$ is the refractive index of organic layer. At the x-o-y plane, the angular distribution for emission intensity of x, y, and z dipoles is calculated by $E_1 = P_x \sin \theta / 4\pi r^3$, $E_2 = P_y \cos \theta / 4\pi r^3$, and $E_3 = P_z / 4\pi r^3$ respectively [29], where $E$ is the angular distribution of oscillating dipole emitting, and $P_x$ is the electric dipole moment, which is constant for fixed dipole, $\varepsilon$ is the dielectric constant of the organic layer, and r is the distance from dipole to a certain point. The curves in Fig. 5 describe the calculated angular emission distribution patterns of the three kinds of dipole freedoms, which change with different Alq3 thickness rapidly.

The calculated dipoles angular emission distributions patterns for small molecule based devices with various thicknesses of Alq3 are shown in Fig. 5(d). Due to the interference between the directly emitted light and the light reflected by the Al cathode, these patterns obviously alter with the distance from dipoles to the metal cathode.

In order to exactly calculate the photon flux of various modes, the light intensity ($I(\theta)$) is integrated at each angle range of the three modes (i.e., $\int_{\text{angle range}} 2\pi \sin \theta I(\theta) d\theta$), and the photon flux of the various modes is obtained. Fig. 6(a) describes the calculated percentage of the three kinds of modes, and the external coupling efficiency $\eta_{\text{ext}}$ under the different thickness of Alq3. When the thickness of Alq3 is 60 nm, the maximal $\eta_{\text{ext}}$ is 43%, and the Alq3 is 150 nm; only 13% of the light escapes the device, and most of the light is trapped in the device. In addition, the external coupling ratio, rext can be also calculated by Fig. 6(a), which was shown in Fig. 6(b), and presented the range of rext from 20% to 56% under the different thickness of Alq3. And the calculated results agreed well with our experiments. Our study will benefit the optimization of device structures for the higher out-coupling efficiency.

The external quantum efficiency ($\eta$) defined as the number of photons emitted into the viewing direction per injected carrier [33], is expressed in the following equation:

$$\eta = \eta_{\text{int}} \eta_{\text{ext}}$$  \hspace{1cm} (6)

The internal quantum efficiency ($\eta_{\text{int}}$) defined as the ratio of the total number of photons generated within the structure to the number of electrons injected. In the small molecule based OLEDs, the maximal $\eta_{\text{int}}$ is 25%, and the maximal external quantum efficiency is about 10%.

We obtained $\eta_{\text{ext}}$ and rext that are higher than some previous calculations. Fig. 7 shows the comparison of dipoles angular emission distribution patterns, which are calculated by the extended half-space dipole model and the former half-space model respectively, where the thickness of Alq3 layer is 60 nm. From the comparison, we can
get that the dipoles radioactive emission at the angle range: \( \theta_1 < \theta < \theta_2 \)

\[ \theta_1 \leq \theta \leq \theta_2 \leq \pi/2 \]

is not as much as the calculation of the former half-space modeling. So the photon flux of the substrate modes and ITO/organic modes is also not high, and then external coupling ratio or external coupling efficiency obtained by our model is higher than some previous anticipation.

### 4. Conclusion

In conclusion, an integrating sphere associating with a fiber spectrometer measurement and an extended “half-space” dipole model by taking dipole radiation pattern into account are developed to describe the external coupling ratio of OLED. We found the maximum external coupling ratio \( (r_{\text{ext}}) \) is about from 20\% to 56\%, which depends on the thickness of the Alq3 layer. The numerical results are in good agreement with our experiments. These results will benefit researchers to improve the light coupling efficiency and optimize the structure of the small molecule based bottom emitting devices.
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